

Bias Resistor Transistor

NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

LDTC123YET1G

- Applications

Inverter, Interface, Driver

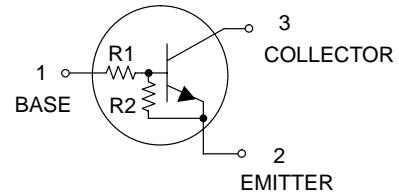
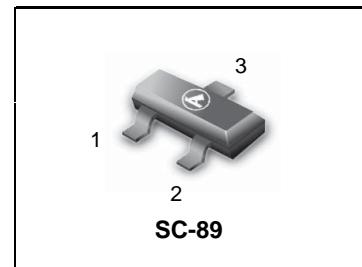
- Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.

- We declare that the material of product compliance with RoHS requirements.

- Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits		Unit
Supply voltage	V _{CC}	50		V
Input voltage	V _{IN}	-5 to +12		V
Output current	I _O	100		mA
	I _{C(Max.)}	100		
Power dissipation	P _D	200		mW
Junction temperature	T _J	150		°C
Storage temperature	T _{STG}	-55 to +150		°C



DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
LDTC123YET1G	N8	2.2	10	3000/Tape & Reel
LDTC123YET3G	N8	2.2	10	10000/Tape & Reel

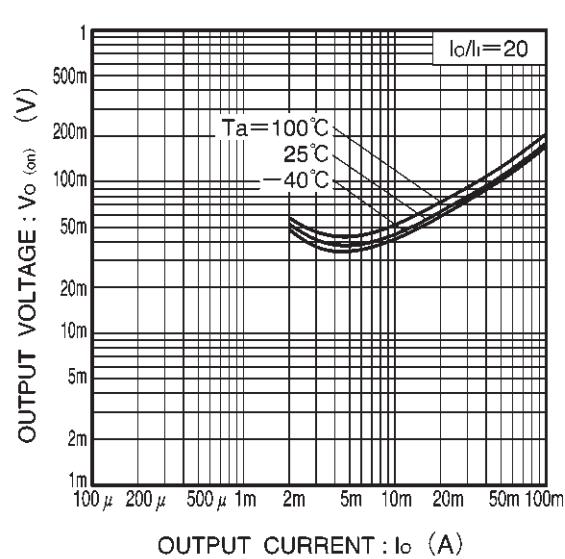
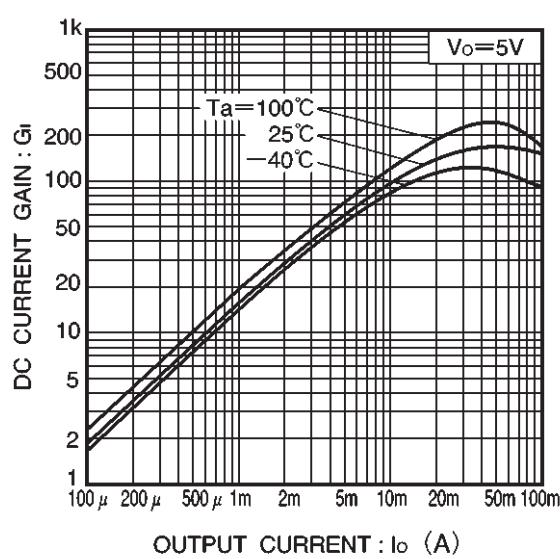
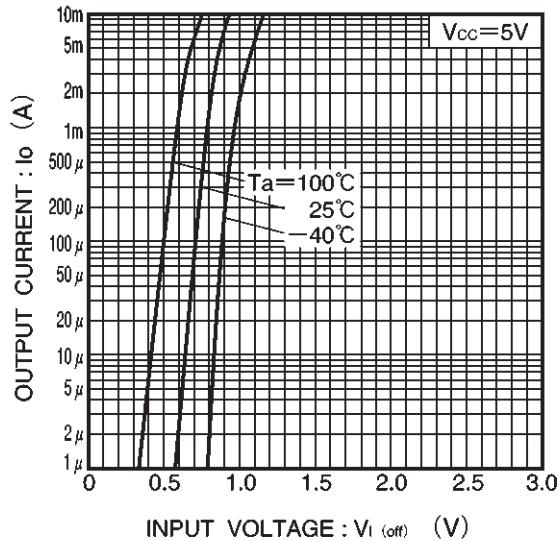
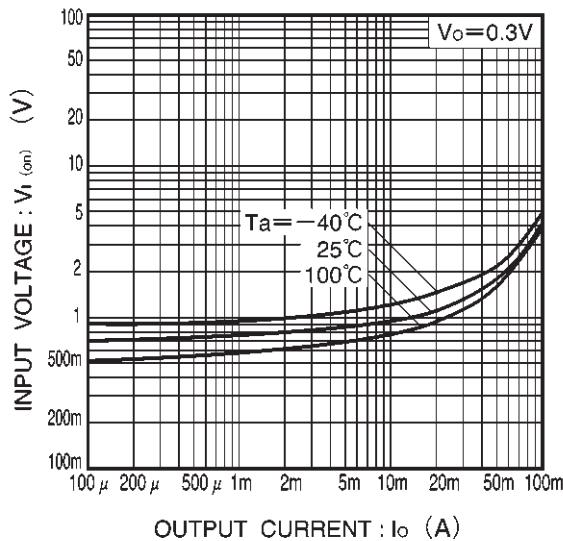
- Electrical characteristics (Ta=25°C)

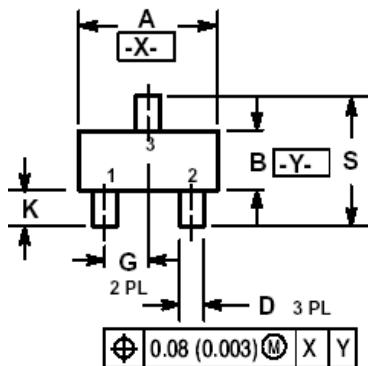
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{I(off)}	—	—	0.3	V	V _{CC} =5V, I _O =100μA
	V _{I(on)}	3	—	—		V _O =0.3V, I _O =20mA
Output voltage	V _{O(on)}	—	0.1	0.3	V	I _O /I _E =10mA/0.5mA
Input current	I _I	—	—	3.8	mA	V _I =5V
Output current	I _{O(off)}	—	—	0.5	μA	V _{CC} =50V, V _I =0V
DC current gain	G _i	33	—	—	—	V _{CC} =5V, I _O =10mA
Input resistance	R _I	1.54	2.2	2.86	kΩ	—
Resistance ratio	R ₂ /R ₁	3.6	4.5	5.5	—	—
Transition frequency	f _T *	—	250	—	MHz	V _{CE} =10V, I _E =-5mA, f=100MHz

* Characteristics of built-in transistor

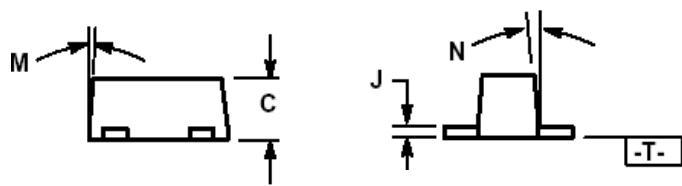
LDTC123YET1G

- Electrical characteristic curves



LDTC123YET1G
SC-89

NOTES:

- 1.DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2.CONTROLLING DIMENSION: MILLIMETERS
- 3.MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4.463C-01 OBSOLETE, NEW STANDARD 463C-02.



DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.50	1.60	1.70	0.059	0.063	0.067
B	0.75	0.85	0.95	0.030	0.034	0.040
C	0.60	0.70	0.80	0.024	0.028	0.031
D	0.23	0.28	0.33	0.009	0.011	0.013
G	0.50 BSC			0.020 BSC		
H	0.53 REF			0.021 REF		
J	0.10	0.15	0.20	0.004	0.006	0.008
K	0.30	0.40	0.50	0.012	0.016	0.020
L	1.10 REF			0.043 REF		
M	---	---	10°	---	---	10°
N	---	---	10°	---	---	10°
S	1.50	1.60	1.70	0.059	0.063	0.067

